

R5528Z SERIES

Overvoltage Protector IC with Reverse Current Protection

NO.EA-313-181010

OUTLINE

The R5528Z001A is a CMOS-based overvoltage protector IC with reverse current protection that use an NMOS pass transistor to achieve ultra-low on resistance (Typ. 54m Ω). Overvoltage protection threshold is as high as 6.8V±3%. Also, continuous current capability is as high as 3A.

Internally, the R5528Z001A consists of a reverse current protection circuit, a soft-start circuit, a startup debounce circuit, an undervoltage lockout (UVLO) circuit, and a thermal shutdown circuit.

The R5528Z001A is offered in a small and thin WLCSP-9-P1 package which achieves the smallest possible footprint solution on boards where area is limited.

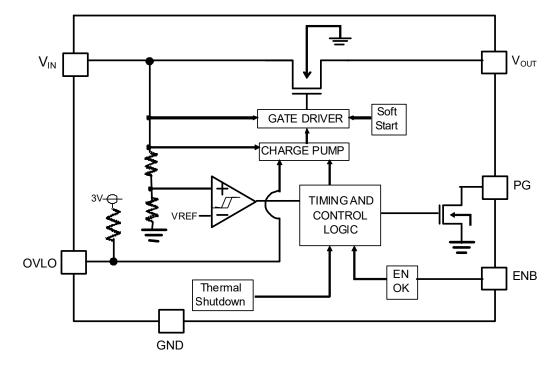
FEATURES

- Input Voltage Range (V_{IN}) ······ 2.3V to 36V
- Output Current (Iout) ······ Max. DC 3A
- Switch On Resistance (R_{ON}) ······ 54mΩ (V_{IN} = 5.0V, I_{OUT} = 100mA)
- OVP Threshold Accuracy ······ 6.8V±3%
- PG Function
- Reverse Current Protection Circuit
- Soft-start Circuit
- Thermal Shutdown Circuit
- Package WLCSP-9-P1 (1.27 mm x 1.27 mm x 0.64 mm)

APPLICATIONS

- Smartphones, Tablet PCs
- Portable devices

BLOCK DIAGRAMS





SELECTION GUIDE

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R5528Z001A-E2-F	WLCSP-9-P1	5,000pcs	Yes	Yes

PIN CONFIGULATIONS

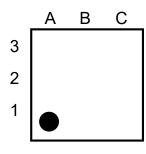


Figure 2. Top View

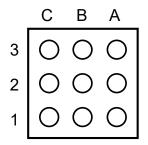


Figure 3. Bottom View

NO.EA-313-181010

PIN DESCRIPTION

Pin No.	Symbol	Pin Description	
A1	PG	Open Drain Flag Output Pin PG is driven low after input voltage is stable between minimum V _{IN} and V _{IN-OVLO} after debounce (delay).	
A2	OVLO	Overvoltage Lockout Input Pin Applying a voltage less than OVLO threshold (V _{OVLO_TH}) to the overvoltage lockout input pin can turn off a switch. When the overvoltage lockout input pin is Open, it outputs an OVLO open voltage (V _{OVLO_OP}).	
A3	ENB	Active-Low ENB Input Pin	
B1, C1	Vin	Input Pin	
B2	I.C	Internally Connected to Ground Unconnected or connected to GND	
B3, C3	Vout	Output Pin	
C2	GND	Ground Pin	

ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Rating	Unit
VIN	Input Voltage	-0.3 to 40	V
Vout	Output Voltage	-0.3 to 8.0	V
VENB	ENB Pin Input Voltage	-0.3 to 6.5	V
V _{PG}	PG Pin Voltage	-0.3 to 6.5	V
Vovlo	OVLO Pin Input Voltage	-0.3 to 6.5	V
IPG	PG Pin Current	14	mA
Іоит	Output Current	3.0	А
PD	Power Dissipation (High Wattage Land Pattern)*1	1190	mW
Topt	Operating Temperature Range	-40 to +85	°C
Tstg	Storage Temerature	-55 to +125	°C

*1 Refer to POWER DISSIPATION for detailed information.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

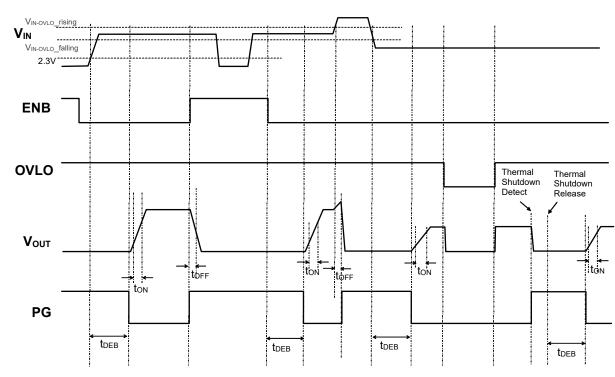
ELECTRICAL CHARACTERISTICS

VIN = 2.3V to 36V, IOUT = 1mA, CIN = 1µF, COUT = 1µF, unless otherwise noted. Typical values are VIN = 5V and Ta = 25°C. The specifications surrounded by are guaranteed by Design Engineering at - $40^{\circ}C \le Ta \le 85^{\circ}C$. (Ta=25°C)

				1	(18	a=25°C)
Symbol	Item	Conditions	Min.	Тур.	Max.	Unit
VIN	Input Voltage		2.3		36	V
lin	Input Supply Current	$V_{ENB} = 0V, V_{IN} = 5V, I_{OUT} = 0mA$		50	120	μA
I _{IN_DIS}	Input Disable Current	$V_{ENB} = 0V, V_{IN} = 5V, V_{OVLO} = 0V$		40	120	μA
lin_q	Input Shutdown Current	$V_{ENB} = 5V, V_{IN} = 5V, V_{OUT} = 0V$		1.0	12	μA
Iout-dis	Output Disable Current	$V_{ENB} = 0V, V_{OUT} = 5V, V_{IN} = 5V,$ $V_{OVLO} < V_{OVLO-TH}$ $V_{ENB} = 0V, V_{OUT} = 5V, V_{IN} > V_{IN-OVLO}$			3	μA
I _{OUT-SD}	Output Shutdown Current	$V_{\text{ENB}} = 5V, V_{\text{OUT}} = 5V, V_{\text{IN}} = 5V$			5.5	μA
Ron	On Resistance	$V_{IN} = 5V, I_{OUT} = 100 \text{mA}$		54	100	mΩ
			6.6	6.8	7.0	V
$V_{\text{IN-OVLO}}$	Overvoltage Protection Threshold	V _{IN} falling	6.4	0.0		V
Соит	OUT Load Capacitance				1000	μF
Vovlo_op	OVLO Open voltage	V _{ENB} = 0V, V _{IN} = 5.0V		3.0	3.6	V
Rovlo_pu	OVLO Pull-up Resistance			500		kΩ
Vovlo_th	OVLO Force Off Voltage		0.6	1.0	1.4	V
VIH	ENB Input High Voltage		1.4			V
VIL	ENB Input Low Voltage				0.4	V
I _{ENB}	ENB Input Leakage		-1		1	μA
Vol	PG Output Low Voltage	I _{SINK} = 1mA			0.4	V
Vpg_leak	PG Leakage Current	$V_{10} = 3.3 V^{*2}$	-1		1	μA
t DEB	IN Debounce Time	starts when $2.3V < V_{IN}(5V) < V_{IN-OVLO}$ and ends when charge-pump is turned on ^{*3}	10	15	35	ms
t _{ss}	Soft-start Time	starts when $2.3V < V_{IN} < V_{IN-OVLO}$ and ends when V_{OUT} = 90% of V_{IN}		30		ms
ton	Turn-on Time During Soft-start	V_{IN} = 5V, R_L = 50 Ω , C_L = 10uF, starts when V_{OUT} = 20% of V_{IN} and ends when V_{OUT} = 80% of V_{IN}^{*3}	1.5	-		ms
toff	Turn-off Time	$\label{eq:RL} \begin{array}{l} R_L = 50\Omega, \\ starts \mbox{ when } V_{IN} > V_{IN-OVLO} \ (2V/\mu s) \mbox{ and ends} \\ \mbox{ when } V_{OUT} = 80\% \mbox{ of } V_{IN} \end{array}$		1.5		μs
		starts when V_{ENB} is switched from "L" to "H", ends when V_{OUT} = 80% of $V_{\text{IN}},$ R_{L} = 50 Ω		84		
T _{SHDN}	Thermal Shut Down			150		°C
T _{HYST}	Thermal Hysteresis			20		°C
VUVREL	UVLO Release Voltage	V _{IN} rising		2.05	2.3	V
VUVHYS	UVLO Hysteresis	V _{IN} falling		0.15		V

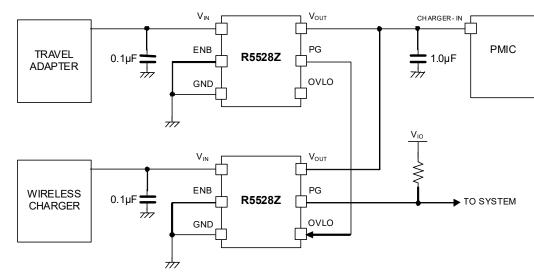
All test items listed under ELECTRICAL CHARACTERISTICS are done under the pulse load condition (Tj≈Ta=25°C) except Soft-Start Time and Turn-off Time and UVLO Hysteresis. ^{*2} Refer to *TYPICAL APPLICATION AND TECHNICAL NOTES*.

*3 Refer to TIMING CHART.



TIMING CHART

Figure 4. Timing Chart



TYPICAL APPLICATIONS AND TECHNICAL NOTES

Figure 5. Typical Applications

Technical Notes

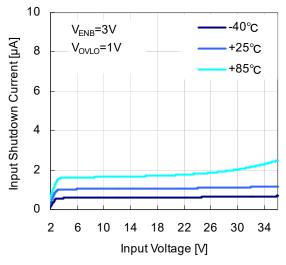
The R5528Z001A does not require any bypass capacitor between V_{IN} and GND. However, connecting a 0.1µF or more capacitor between V_{IN} and GND may improve the performance against the noise.

If there's any possibility of generating spike noise due to the parasitic element (inductance) of V_{IN} , connect an appropriate-sized capacitor between V_{IN} and GND.

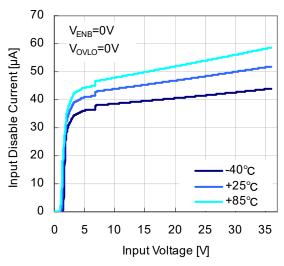
NO.EA-313-181010

TYPICAL CHARACTERISTIC

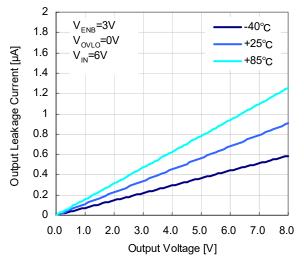
1) Input Shutdown Current VS. Input Voltage R5528Z001A



3) Input Disable Current VS. Input Voltage R5528Z001A

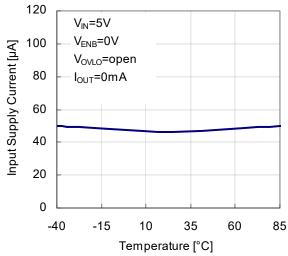


5) Output Leakage Current (6V) VS. Output Voltage R5528Z001A

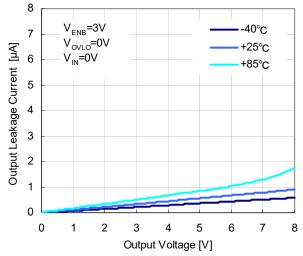


70 V_{ENB}=0V 60 V_{OVLO}=3V Input Supply Current [µA] 50 40 30 -40°C 20 +25°C 10 +85°C 0 0 5 10 35 15 20 25 30 Input Voltage [V]

4) Input Supply Current VS. Temperature R5528Z001A

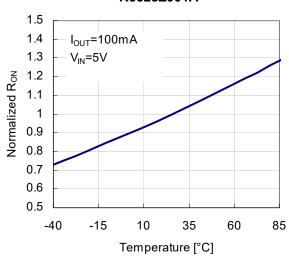


6) Output Leakage Current (0V) VS. Output Voltage R5528Z001A



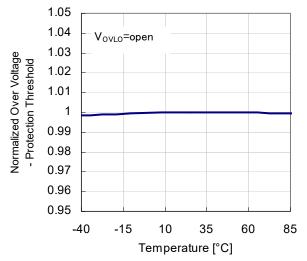
2) Input Supply Current VS. Input Voltage R5528Z001A

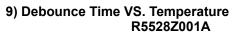
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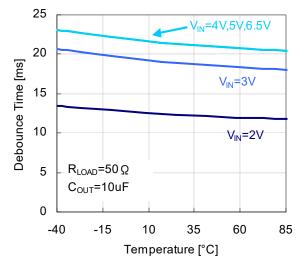


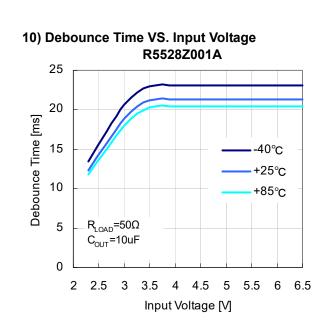
7) Normalized On-Resistance VS. Temperature R5528Z001A

8) Normalized Overvoltage Protection Threshold (IN rising) VS. Temperature R5528Z001A

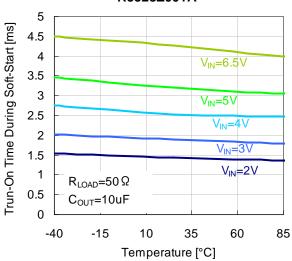




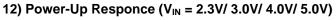




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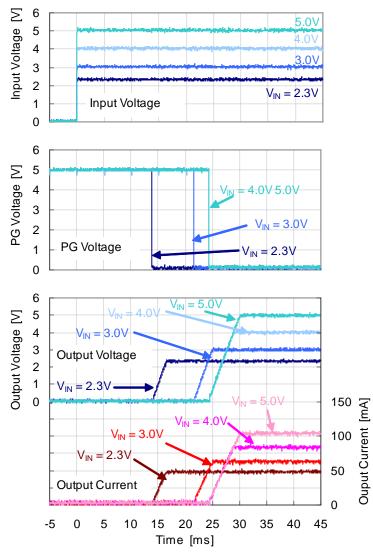


11) Trun-On Time VS. Temperature R5528Z001A



R5528Z001A

 $R_{\text{LOAD}} = 50 \Omega / C_{\text{OUT}} = 10 \mu F / PG = 10 K \Omega \text{ to} 5 V / V_{\text{ENB}} = 0 V / Ta = 25^{\circ} C$

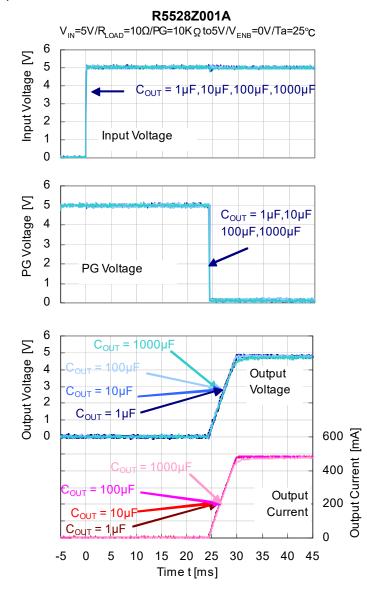


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R5528Z001A $V_{\text{IN}}=5.0V/C_{\text{OUT}}=10\mu\text{F/PG}=10K\Omega\text{ to}5V/V_{\text{ENB}}=0V/Ta=25^{\circ}\text{C}$ Input Voltage [V] $R_{LOAD} = 10\Omega, 50\Omega, 500\Omega, 5K\Omega$ 1 Input Voltage 0 6 $R_{LOAD} = 10\Omega, 50\Omega,$ PG Voltage [V] 5 500Ω, 5ΚΩ PG Voltage 4 3 2 1 0 6 5 $R_{LOAD} = 10\Omega, 50\Omega,$ 4 500 500Ω, 5ΚΩ Output Current lour [mA] 3 10Ω Output Voltage Vour [V] 2 400 **Output Voltage** 1 0 300 Output Current 200 50Ω $R_{LOAD} = 5k\Omega$ 100 500Ω 0 -5 5 10 15 20 25 30 35 40 45 0 Time t [ms]

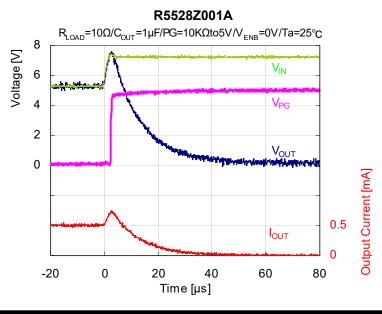
13) Power-Up Responce ($R_{LOAD} = 10\Omega / 50\Omega / 500\Omega / 5K\Omega$)

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14) Power-Up Responce (Cout = 1µF/ 10µF/ 100µF/ 1000µF)





POWER DISSIPATION

WLCSP-9-P1

Ver. A

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following conditions are used in this measurement.

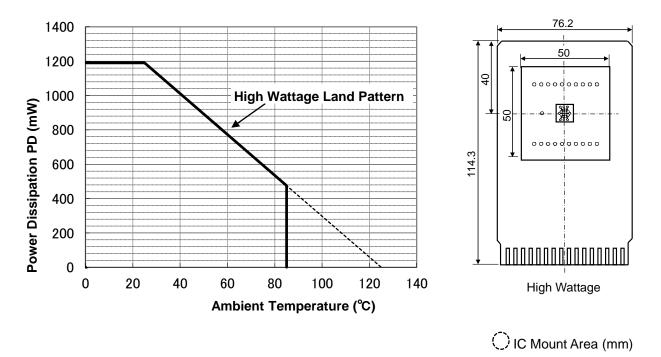
Measurement Conditions

	High Wattage Land Pattern	
Environment	Mounting on Board (Wind Velocity = 0 m/s)	
Board Material	Glass Cloth Epoxy Plastic (Four-layers)	
Board Dimensions	76.2 mm × 114.3 mm × 1.6 mm	
Copper Ratio Outer Layers (First and Fourth Layers): Approx. 60% Inner Layers (Second and Third Layers): 100%		

Measurement Result

(Ta = 25°C, Tjmax = 125°C)

	High Wattage Land Pattern	
Power Dissipation	1190 mW	
Thermal Resistance $\theta ja = (125 - 25^{\circ}C) / 1.19 W = 84^{\circ}C/W$		



RICOH

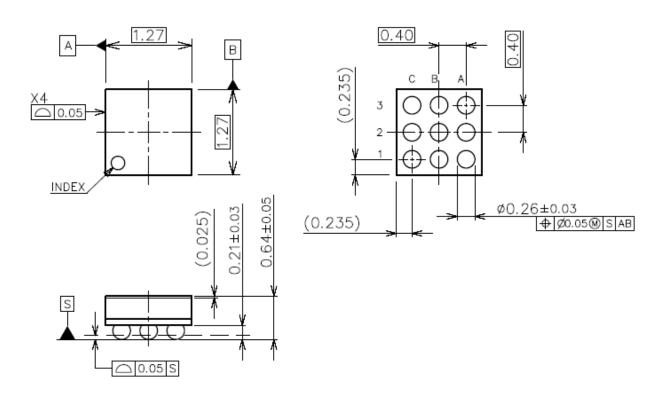
Power Dissipation vs. Ambient Temperature

Measurement Board Pattern

PACKAGE DIMENSIONS

WLCSP-9-P1

Ver. A



WLCSP-9-P1 Package Dimensions (Unit: mm)

RICOH

VISUAL INSPECTION CRITERIA

WLCSP

VI-160823

No.	Inspection Items	Inspection Criteria	Figure
1	Package chipping	A≥0.2mm is rejected B≥0.2mm is rejected C≥0.2mm is rejected And, Package chipping to Si surface and to bump is rejected.	B ↓ C
2	Si surface chipping	A≥0.2mm is rejected B≥0.2mm is rejected C≥0.2mm is rejected But, even if A≥0.2mm, B≤0.1mm is acceptable.	B t C
3	No bump	No bump is rejected.	
4	Marking miss	To reject incorrect marking, such as another product name marking or another lot No. marking.	
5	No marking	To reject no marking on the package.	
6	Reverse direction of marking	To reject reverse direction of marking character.	
7	Defective marking	To reject unreadable marking. (Microscope: X15/ White LED/ Viewed from vertical direction)	
8	Scratch	To reject unreadable marking character by scratch. (Microscope: X15/ White LED/ Viewed from vertical direction)	
9	Stain and Foreign material	To reject unreadable marking character by stain and foreign material. (Microscope: X15/ White LED/ Viewed from vertical direction)	

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